

FEATURES

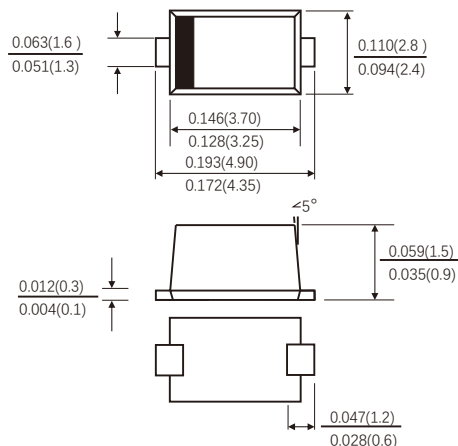
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2015/863/EU



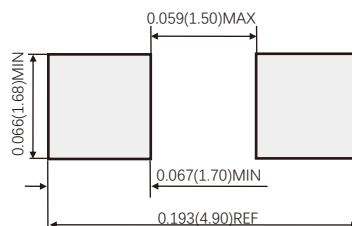
MECHANICAL DATA

- Case: SMAF molded plastic body
- Terminals: Solder Plated, solderable per MIL-STD-750,method 2026
- Polarity: Color band denotes cathode end

SMAF



Suggested PAD Layout



Dimensions in inches and (millimeters)

TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters, free wheeling ,and polarity protection applications

MAXIMUM RATINGS

(Ratings at 25°C ambient temperature unless otherwise specified)

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	60	V
Maximum average forward rectified current (see fig.1)	$I_F(AV)$	5.0	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated TL)	I_{FSM}	120	A
Operating junction temperature range	T_J	-55 to+150	°C
Storage temperature range	T_{stg}	-55 to+150	°C

ELECTRICAL CHARACTERISTICS (T_A=25°C Unless otherwise noted)

Parameter	Test Conditions		Symbol	Typ.	Max.	Unit
Instantaneous forward voltage	T _J =25°C	I _F =1.0A	V _F ¹⁾	0.33	-	V
		I _F =3.0A		0.40	-	
		I _F =5.0A		0.46	0.52	
	T _J =125°C	I _F =1.0A		0.24	-	
		I _F =3.0A		0.35	-	
		I _F =5.0A		0.44	-	
Reverse current	V _R =60V	T _J =25°C	I _R ²⁾	-	150	μA
		T _J =100°C		5	-	mA
		T _J =125°C		15	-	
Typical junction capacitance	4V,1MHz		C _J	670		pF

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Pulse test: pulse width ≤40ms

THERMAL CHARACTERISTICS

Parameter	Symbol	SMAF	Unit
Typical thermal resistance ³⁾	R _{θJA}	65	°C/W
	R _{θJL}	20	

3.P.C.B. mounted with 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas (≥40μm thick)

The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_C/dT_J < 1/R_{\theta JA}$

AVAILABLE PACK INFORMATION

Product code	Pack	Reel Size (mm)	Quantity (pcs/reel)	Box Size L×W×H (mm)	Quantity (reel/box)	Carton Size L×W×H (mm)	Quantity (box/carton)	Quantity(carton) (K)
SS56SLS-SMAF	T/R	Φ178	3000	180×180×105	6	550×200×205	5	90

RATINGS AND CHARACTERISTIC OF SS56SLS

FIG.1-FORWARD CURRENT DERATING CURVE

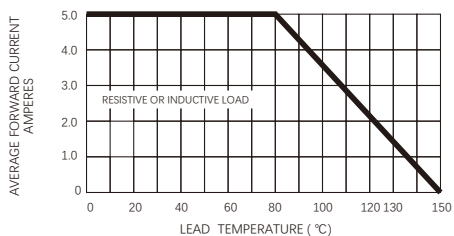


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

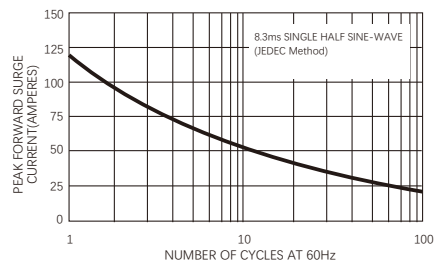


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

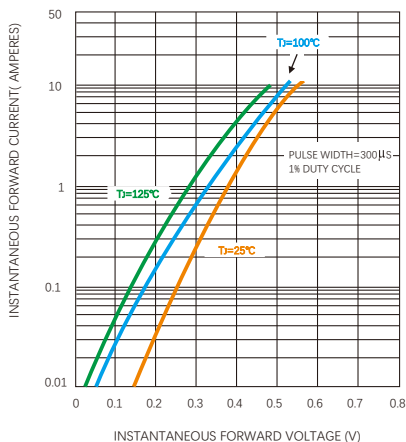


FIG.4-TYPICAL REVERSE CHARACTERISTICS

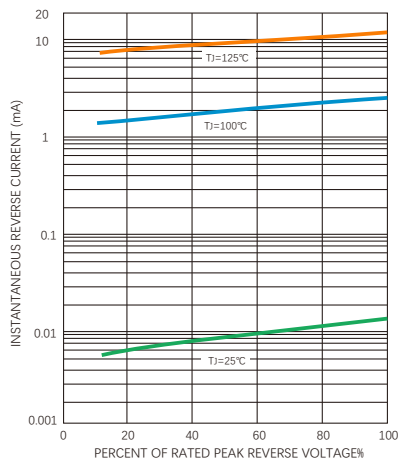
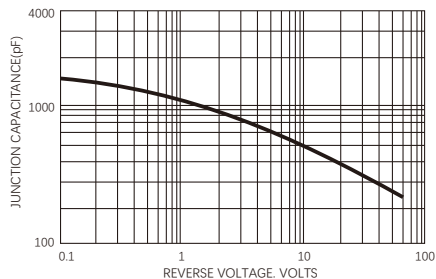


FIG.5-TYPICAL JUNCTION CAPACITANCE



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